



### 20V P-Channel Enhancement Mode MOSFET

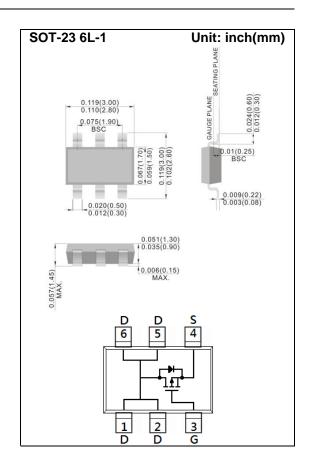
Voltage -20 V Current -6.5A

#### **Features**

- RDS(ON), VGS@-4.5V, ID@-6.5A<35mΩ
- RDS(ON) , VGS@-2.5V, ID@-4.6A<40mΩ</li>
- RDS(ON), VGS@-1.8V, ID@-2.6A<50mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case: SOT-23 6L-1 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.0141 grams
- Marking: S17



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	-20	V
Gate-Source Voltage		V <sub>G</sub> s	<u>+</u> 8	V
Continuous Drain Current		I <sub>D</sub>	-6.5	Α
Pulsed Drain Current		I <sub>DM</sub>	-26	А
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	2	W
	Derate above 25°C		16	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> ,T <sub>STG</sub>	-55~150	°C
Typical Thermal Resistance				
- Junction to Ambient (Note 3)		R <sub>θJA</sub>	62.5	°C/W





### **Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-20	-	ı	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-0.35	-0.59	-0.9	<b>V</b>
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-6.5A	-	29	35	mΩ
		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-4.6A	-	33	40	
		V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-2.6A	-	40	50	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V	-	-0.01	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 8V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic						
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-10V, I <sub>D</sub> =-6.5A, V <sub>GS</sub> =-4.5V (Note 1,2)	-	18.9	ı	nC
Gate-Source Charge	$Q_gs$		-	2.8	-	
Gate-Drain Charge	$Q_{gd}$		-	4.2	ı	
Input Capacitance	Ciss	V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V, f=1.0MHZ	-	1760	-	pF
Output Capacitance	Coss		-	148	ı	
Reverse Transfer Capacitance	Crss		-	120	-	
Switching						
Turn-On Delay Time	td <sub>(on)</sub>	$\begin{array}{c} V_{DS}\text{=-}10V,\ I_{D}\text{=-}6.5A, \\ V_{GS}\text{=-}4.5V, \\ R_{G}\text{=-}6\Omega \ ^{\text{(Note 1.2)}} \end{array}$	-	12	-	ns
Turn-On Rise Time	tr			68		
Turn-Off Delay Time	td <sub>(off)</sub>		-	82	-	
Turn-Off Fall Time	tf		-	35	ı	
Drain-Source Diode						
Maximum Continuous Drain-Source	la				-2.0	Α
Diode Forward Current	Is		_	-	-∠.∪	А
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-1.0A, V <sub>GS</sub> =0V	-	-0.69	-1.2	V

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





#### **TYPICAL CHARACTERISTIC CURVES**

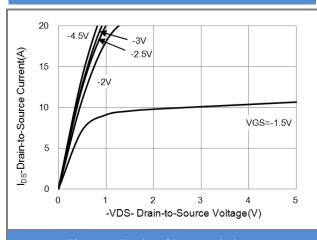
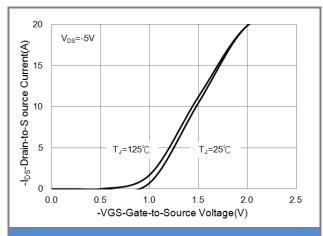


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

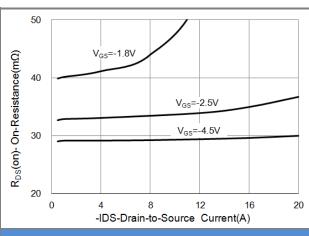


Fig.3 On-Resistance vs. Drain Current

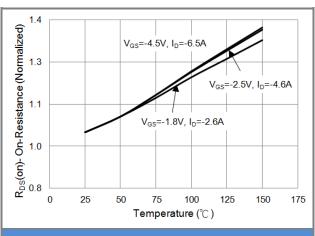


Fig.4 On-Resistance vs. Junction temperature

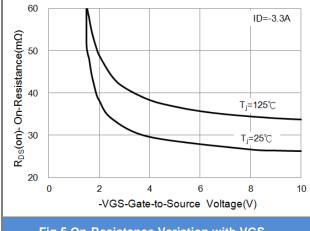
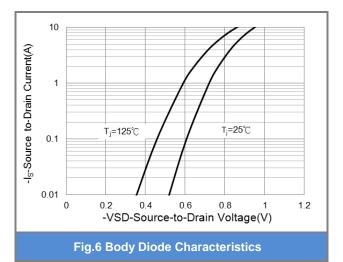


Fig.5 On-Resistance Variation with VGS.







### **TYPICAL CHARACTERISTIC CURVES**

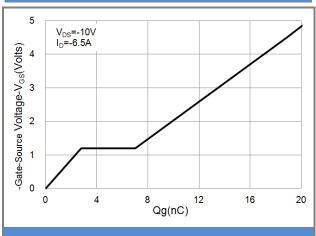


Fig.7 Gate-Charge Characteristics

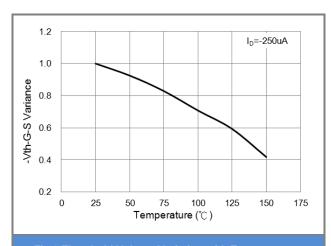


Fig.8 Threshold Voltage Variation with Temperature

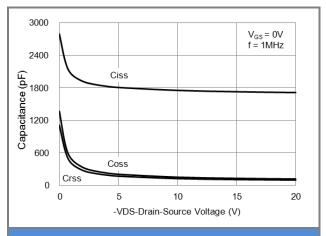


Fig.9 Threshold Voltage Variation with Temperature.

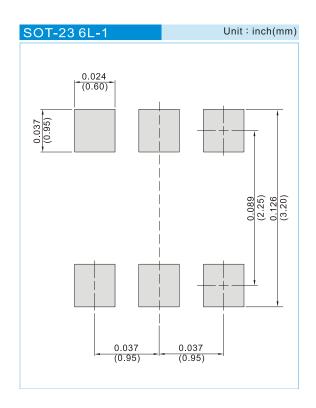




### PART NO. PACKING CODE VERSION

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJS6417_S1_00001	SOT-23 6L-1	3K pcs / 7" reel	S17	Halogen free RoHS compliant

### **MOUNTING PAD LAYOUT**







### Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are
  responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no
  representation or warranty that such applications will be suitable for the specified use without further testing or
  modification.
- The products shown herein are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, transportation equipment, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

# Panjit:

PJS6417\_S1\_00001